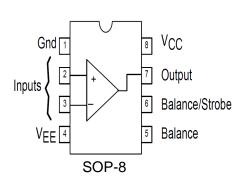


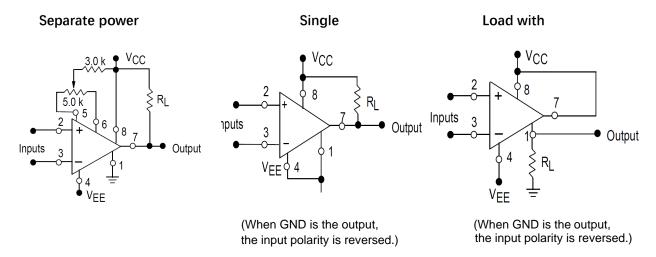
Summary

LM311DR and LM211DR can work on a single power supply of 5V to 30V or a dual power supply of ±15V. Like the commonly used comparator, LM311 can become a real universal comparator. The input ofLM311DR and LM211DR can be isolated from the system, and the output can be referenced to ground, power supply or VEE. This flexibility can drive DTL, RTL, TTL or MOS level logic. When the output current is 50MA, the output can switch the voltage to 50V, which can be used to drive relays, lamps or solenoids.

Pin arrangement diagram



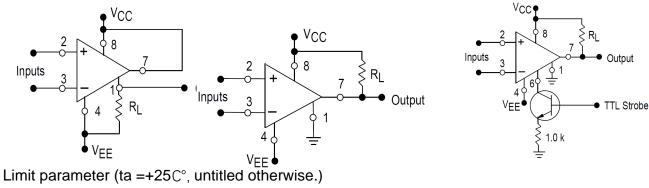
Typical comparator design scheme





Load referenced to negative power supply positive power supply

High flexibility voltage comparator Gating ability



Rating	Symbol	LM211 LM311		Unit	
Total supply voltage	VCC + VEE	36 36		Vdc	
Output to negative supply voltage	VO -VEE	50 40		Vdc	
Ground to negative power supply	VEE	30	30	Vdc	
Input differential voltage	VID	30	30	Vdc	
Input voltage (Note 2)	V _{in}	15	15	Vdc	
Strobe pin voltage gating	_	VCC to VCC-5	VCC to VCC-5	Vdc	
Power consumption and thermal characteristics plastic package DIP Ta decreases when it exceeds 25°C	PD	62 5.	mW mW/℃		
operating ambient temperature	ТА	-25 to +85	0 to +70	$^{\circ}$	
operating junction temperature range	T _{J(max)}	+150	+150	$^{\circ}$	
storage temperature	T _{stg}	-65 to +150	-65 to +150	$^{\circ}$	

Electrical characteristics (VCC =+15 V, VEE =-15 V, TA = 25°, UNLESS Otherwise Noted [Note 1].)

parameter		T 3 5011			T 3 5011			
		LM211			LM311			Unit
·	Symbol	Min	Тур	Max	Min	Тур	Max	Oilit
Input offset voltage (Note 3)	VIO							mV
$RS \le 50 \text{ k}$, $TA = +25^{\circ}C$		_	0.7	3.0	-	2.0	7.5	
$R_{S \le 50 \text{ k}}$, $T_{low \le TA \le Thigh}^*$		_	_	4.0	ı	_	10	
Offset current (Note 3) T _A = +25°C	ΙΙΟ	_	1.7	10	-	1.7	50	nA
$T_{low \le} T_{A \le} T_{high}^*$		_	_	20	ı	_	70	
Input bias current T _A = +25°C T _{low} ≤ T _A ≤T _{high} *	IIB	_	45	100	_	45	250	nA
		_	_	150	ı	_	300	
Voltage gain	Ay	40	200	_	40	200	-	V/mV



parameter		LM211			LM311			
		Min	Тур	Max	Min	Тур	Max	Unit
Response time (Note 4)		ı	200	_	ı	200	-	ns
Output saturation pressure drop	VOL							V
$VID \le -5.0 \text{ mV}$, $Io = 50 \text{ mA}$, $TA = 25C \text{ VID} \le -10 \text{ mV}$, IO		_	0.75	1.5	_	_	_	
= 50 mA, TA = 25C		_	_	_	_	0.75	1.5	
VCC≥ 4.5 V, VEE= 0, Tlow≤ TA≤ Thigh* VID≤6.0 mV								
Isink ≤ 8.0 mA		_	0.23	0.4	_	_	_	
VID≤10 mV lsink ≤ 8.0 mA		_	_	_	_	0.23	0.4	
Gated on current (Note 5)	Is	_	3.0	_	_	3.0	_	mΑ
Output leakage current								
$V_{\text{ID}} \le 5.0 \text{ mV}$, V_{O} = 35 V, T_{A} = 25 $^{\circ}$ C, I_{strobe} = 3.0 mA V_{ID}		_	0.2	10	_	_	_	nA nA
\leq 10 mV, VO= 35 V, TA = 25 $^{\circ}$ C, Istrobe= 3.0 mA VID \leq 5.0		_	_	_	_	0.2	50	uA
mV , $VO = 35 V$, $Tlow \le TA \le Thigh*$		_	0.1	0.5	_	_	_	
Input voltage (tlow ≤ ta ≤ thick *)	VICR	-14.5	-14.7	+13.0	-14.5	-14.7	+13.0	V
			to 13.8			to 13.8		
Positive supply current	ICC	_	+2.4	+6.0	_	+2.4	+7.5	mA
Negative supply current	IEE	_	-1.3	-5.0	_	-1.3	-5.0	mA

^{*} Tlow=-25 C corresponds to Im 211, and tlow = 0 c corresponds to LM311.

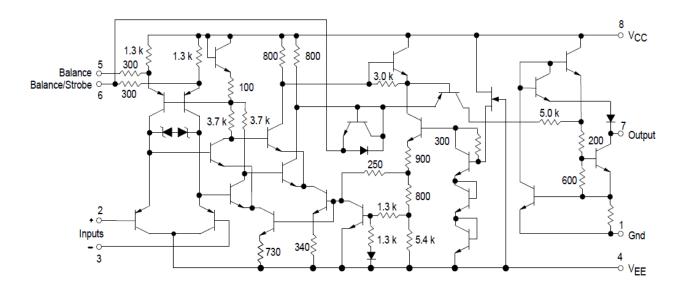
NOTES:1. The specifications of offset voltage, offset current and bias current correspond to the power supply voltage of 5V to ±15V.

- 2. This rating is for the case of ±15V power supply. The positive input voltage limit is 30V higher than the negative power supply, and the negative input limit is equivalent to the negative power supply voltage, or 30V lower than the power supply, or whichever is smaller.
- 3. Given offset voltage and offset current, it is required to drive a load with a maximum value of 1mA in any power supply voltage range, and these parameters define the error range, thus taking the worst case of voltage gain and input impedance into account.
- 4. The specified response time is 100Mv input plus 5MV overdrive signal.
- 5. Don't directly ground the STROBE pin, it needs to be driven by 3mA~5mA current.

^{*} Thigh=85 C corresponds to Im 211, and Thigh = 75 c corresponds to LM311.

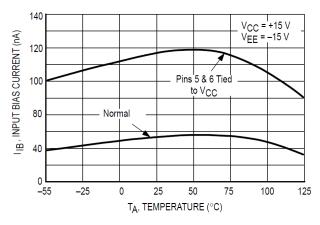


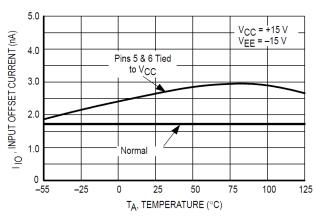
schematic circuit diagram



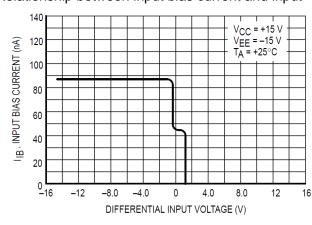
Relationship between input bias current and temperature

Relationship between input offset current and temperature

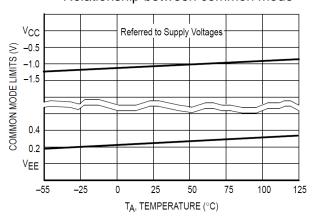




Relationship between input bias current and input

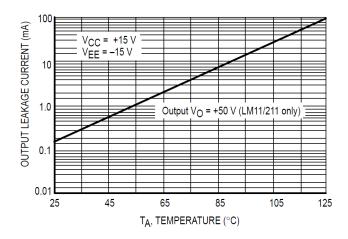


Relationship between common mode



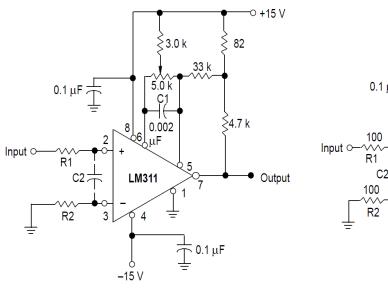


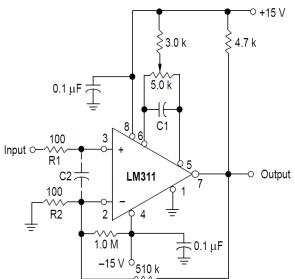
Relationship between output leakage current and temperature



An improved method without inpu positive feedback and laghysteresis

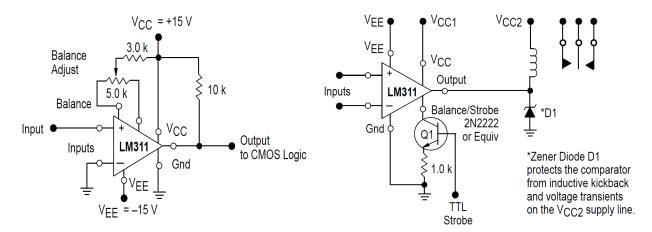
Techniques for adding





Zero-crossing detector driving CMOS logic

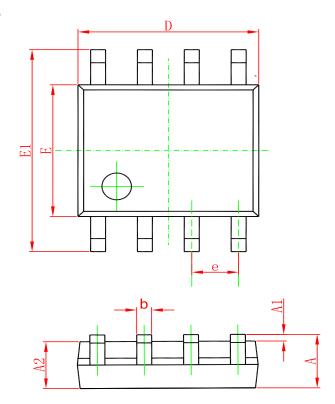
Relay driver with gating capability

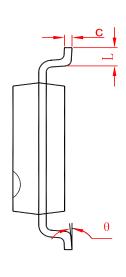




PACKAGE OUTLINE DIMENSIONS

SOP-8

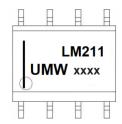


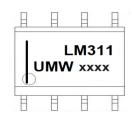


Cymhol	Dimensions In Millimeters		Dimensions I	n Inches	
Symbol	Min	Max	Min	Max	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	(BSC)	0.050(BSC)		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



Marking





Ordering information

Order code	Package	Baseqty	Deliverymode
UMW LM311DR	SOP-8	2500	Tape and reel
UMW LM211DR	SOP-8	2500	Tape and reel